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PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/749,650	12/30/2003	Tae-Hee Park	20067/OPP031479US	9404	
34431 759	90 04/15/2005		EXAM	INER	
HANLEY, FLIGHT & ZIMMERMAN, LLC 20 N. WACKER DRIVE			LEE, GRANVILL D		
SUITE 4220	RDRIVE		ART UNIT	PAPER NUMBER	
CHICAGO, IL	60606		2891 DATE MAILED: 04/15/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

	Applicati	on No.	Applicant(s)					
				(Oh)				
Office Action Summary	10/749,6		PARK, TAE-HEE	CB				
Office Action Summary	Examine		Art Unit					
	Granvill D	•	2891					
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).								
Status				·				
1) Responsive to communication(s) filed	on <u>05 May 2004</u> .							
2a) This action is FINAL.								
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is								
closed in accordance with the practice	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims								
4)⊠ Claim(s) <u>1-14</u> is/are pending in the ap	plication.	• '						
4a) Of the above claim(s) is/are	•	nsideration.						
5) Claim(s) is/are allowed.								
6)⊠ Claim(s) <u>1</u> is/are rejected.								
7)⊠ Claim(s) <u>2-14</u> is/are objected to.								
8) Claim(s) are subject to restriction and/or election requirement.								
Application Papers								
9) The specification is objected to by the Examiner.								
10)⊠ The drawing(s) filed on <u>30 December 2003</u> is/are: a) accepted or b) objected to by the Examiner.								
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority under 35 U.S.C. § 119			•					
12)⊠ Acknowledgment is made of a claim fo	or foreian priority un	der 35 U.S.C. § 119(a)-(d) or (f).					
a)⊠ All b)□ Some * c)□ None of:			-, (-, -, (-,					
1.⊠ Certified copies of the priority documents have been received.								
2. Certified copies of the priority documents have been received in Application No								
3. Copies of the certified copies of the priority documents have been received in this National Stage								
application from the International Bureau (PCT Rule 17.2(a)).								
* See the attached detailed Office action for a list of the certified copies not received.								
		•						
Attachment(s)								
 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PT 	0-048)	4) Interview Summar Paper No(s)/Mail I	ry (PTO-413) Date					
3) Information Disclosure Statement(s) (PTO-1449 or P			Patent Application (PTO-1	52)				
Paper No(s)/Mail Date <u>5/5/2004</u> .	,	6) Other:	·					
U.S. Patent and Trademark Office PTOL-326 (Rev. 1-04)	Office Action Summa	ry F	Part of Paper No./Mail Date	04042005				

DETAILED ACTION

Specification

The disclosure is objected to because of the following informalities: The paragraph beginning with "To whom it may concern...", is not needed and should be deleted. Appropriate correction is required.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 1 is rejected under 35 U.S.C. 103(a) as being unpatentable over Hwang et al. (US. Pat. 6,323,132) in view of Pu et al. (US. Pat. 5,843,847). Hwang et al. discloses a method for forming a metal line or circuit element in a semiconductor device (Col. 16 lines 1-5), the method comprising: forming a lower adhesive layer (Fig. 6 #14) consisting of titanium or titanium nitride on a semiconductor substrate (Col. 16 lines 32-40); forming a metal layer (#16) including aluminum (Col. 23 lines 15-20) on the lower adhesive layer; forming an anti-reflection or protective layer (#22) on the metal layer;

forming a photomask (#18) on the anti-reflection layer; performing an initial etching (Fig. 8), a main etching (Fig. 9) and an over-etching (Fig. 16) for the anti-reflection layer (#22), the metal layer (#16) and the lower adhesive layer (#14), respectively (Col. 9 lines 20-50), in a region which is not protected (as shown) by the photomask, using C3F8 as a main etching gas; and removing the photomask (#18) residual on the anti-reflection layer (Col. 16 lines 57-65).

Yet, Hwang et al. fails to suggest an etching gas of C3F8 utilized as the main etching gas component for the number of etchings used. However, Pu et al. suggests that C₃F₈ etching gas (Col. 5 line 60-Col. 6 line 10) can be easily used to etch materials on substrates, where selectivity is important.

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the circuit element etching technique of Hwang et al. in favor of the C₃F₈ etching gas method of Pu et al. with the idea of achieving better selectivity and etch rate results. Pu et al. sought a method where gas composition selectivity (Col. 1 lines 35-55) ratios were optimized, while still considering the high etch rates, and found that a balance could be met by using an etching gas of the group of CF gases including C₃F₈ etching gas (Col. 5 line 55-Col. 6 line 25).

Allowable Subject Matter

Claims 2-14 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

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The following is an examiner's statement of reasons for possible allowance: The prior art of record does suggest (i.e. Pu et al.) or discloses an etching gas to etch a metal layer to include N₂, but the prior art fails to describe or suggest *inter alia* the invention of including C₃F₈, N₂ and NF₂ gases to etch a metal layer, as claimed. For these reasons, the claims cited define over the prior art. Any comments considered necessary by applicant must be submitted no later than the payments of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Contact Information

Any inquiry concerning this communication or earlier communications for the examiner should be directed to Granvill Lee whose telephone number is (571) 272-1897. The examiner can be normally reached on Monday thru Friday from 8:00 am to 4:30 pm.

If attempts to reach the examiner by telephone are not successful, the examiner's supervisor, Bill Baumeister can be reached on (571) 272-1722. The fax phone number for this group is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see

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http://pair-direct.uspto.gov. Should you have questions on access to thePrivate PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Examiner Granvill Lee Art Unit 2891

Gl 4/5/05

> DAVID ZAPNEKE PRIMARY EXAMINER